August 2005

FAN5330
High Efficiency Serial LED Driver with 30V Integrated Switch

Features

- 1.5MHz Switching Frequency
- Low Noise
- Adjustable Output Voltage
- 0.7W Output Power Capability
- Low Shutdown Current: <1µA
- Cycle-by-Cycle Current Limit
- Low Feedback Voltage (110mV)
- Over-Voltage Protection
- Fixed-Frequency PWM Operation
- Internal Compensation
- Thermal Shutdown
- 5-Lead SOT23 Package

Applications

- Cell Phones
- PDAs
- Handheld Equipment
- Display Bias
- LED Bias

Description

The FAN5330 is an LED driver that features fixed frequency mode operation and an integrated FET switch. This device is designed to operate at high switching frequencies in order to minimize switching noise measured at the battery terminal of hand-held communications equipment. Quiescent current in both normal and shutdown mode is designed to be minimal in order to extend battery life. Normal or shutdown mode can be selected by a logic level shutdown circuitry.

The low ON-resistance of the internal N-channel switch ensures high efficiency and low power dissipation. A cycle-by-cycle current limit circuit keeps the peak current of the switch below a typical value of 1.5A. The FAN5330 is available in a 5-lead SOT23 package.

Typical Application

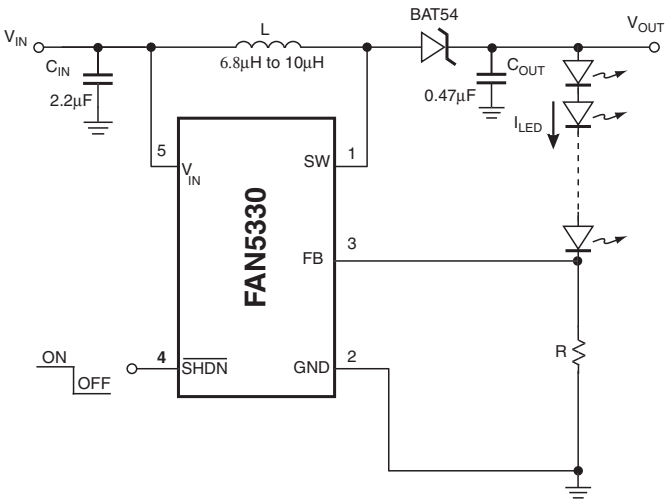
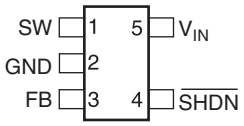


Figure 1. Typical Application Diagram

Pin Assignment

Top View



5-Lead SOT-23

Figure 2. Pin Assignment

Pin Description

Pin No.	Pin Name	Pin Description
1	SW	**Switching Node.**
2	GND	**Analog and Power Ground.**
3	FB	**Feedback Pin.** Feedback node that connects to an external current set resistor.
4	$\overline{SHDN}$	**Shutdown Control Pin.** Logic HIGH enables, logic LOW disables the device.
5	V_{IN}	**Input Voltage Pin.**

Absolute Maximum Ratings (Note1)

Parameter		Min.	Max.	Unit
V_{IN} to GND			6.0	V
FB, $\overline{SHDN}$ to GND		-0.3	V_{IN} + 0.3	V
SW to GND		-0.3	35	V
Lead Soldering Temperature (10 seconds)			300	°C
Junction Temperature			150	°C
Storage Temperature		-55	150	°C
Thermal Resistance (Θ_{JA})			210	°C/W
Electrostatic Discharge Protection (ESD) Level (Note 2)	HBM	2		KV
	CDM	1		

Recommended Operating Conditions

Parameter	Min.	Typ.	Max.	Unit
Input Voltage	1.8		5.5	V
Output Voltage	V_{IN}		30	V
Operating Ambient Temperature	-40	25	85	°C
Output Capacitance Rated at the Required Output (Note 3)	0.1			µF

Notes:

1. Stresses above those listed under “Absolute Maximum Ratings” may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Absolute maximum ratings apply individually only, not in combination.
2. Using EIA/JESD22A114B (Human Body Model) and EIA/JESD22C101-A (Charge Device Model).
3. This load capacitance value is required for the loop stability. Tolerance, temperature variation, and voltage dependency of the capacitance must be considered. Typically a 0.47µF ceramic capacitor is required to achieve specified value at V_{OUT} = 30V.

Electrical Characteristics

Unless otherwise noted, V_{IN} = 3.6V, I_{LED} = 20mA, T_A = -40°C to 85°C, Typical values are at T_A = 25°C, Test Circuit, Figure 3.

Parameter	Conditions	Min.	Typ.	Max.	Units
Feedback Voltage		99	110	121	mV
Switch Current Limit	V_{IN} = 3.2V	1.1	1.5		A
Load Current Capability	$V_{OUT} \leq$ 20V V_{IN} = 3.2V	35			mA
Switch On-resistance	V_{IN} = 5V		0.6		Ω
	V_{IN} = 3.6V		0.7		Ω
Quiescent Current	$V_{\overline{SHDN}}$ = 3.6V, No Switching		0.6		mA
OFF Mode Current	$V_{\overline{SHDN}}$ = 0V		0.1	3	µA
Shutdown Threshold	Device ON	1.5			V
	Device OFF			0.5	V
Shutdown Pin Bias Current	$V_{\overline{SHDN}}$ = 0V or $V_{\overline{SHDN}}$ = 5.5V		1	300	nA
Feedback Pin Bias Current			1	300	nA
Feedback Voltage Line Regulation	2.7V < V_{IN} < 5.5V, $V_{OUT} \leq$ 20V		0.3		%
Switching Frequency		1.25	1.5	1.75	MHz
Maximum Duty Cycle		87	93		%
Switch Leakage Current	No Switching, V_{IN} = 5.5V			1	µA
OVP			15		%
Thermal Shutdown Temperature			150		°C

Test Circuit

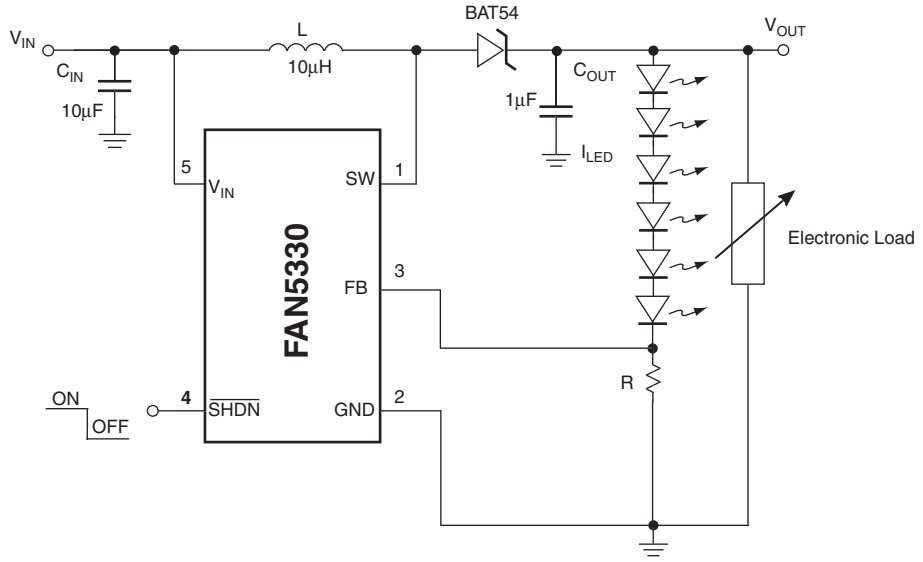
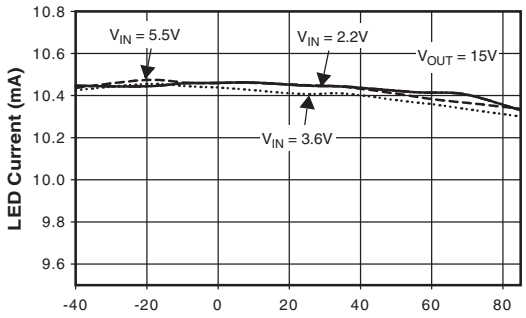


Figure 3. Test Circuit

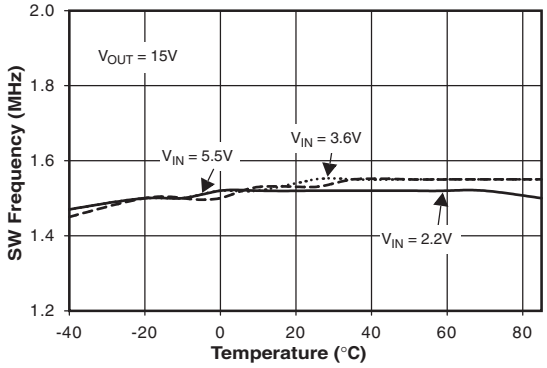
Typical Performance Characteristics

T_A = 25°C, C_{IN} = 4.7µF, C_{OUT} = 0.47µF, L = 10µH, unless otherwise noted.

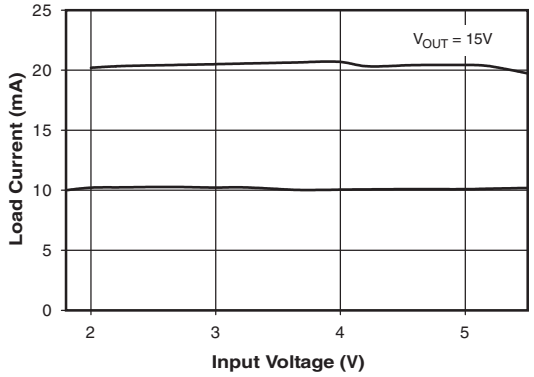
LED Current vs Temperature



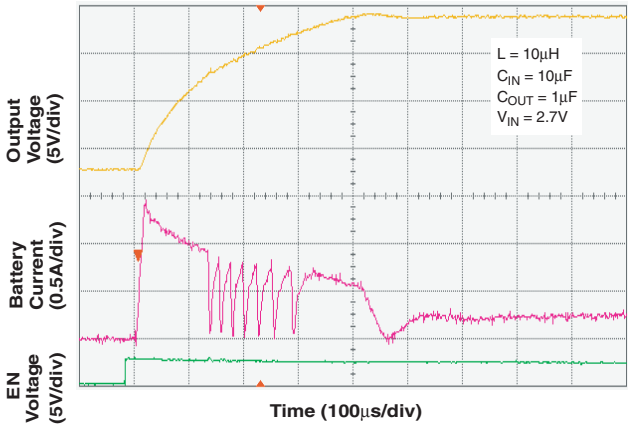
SW Frequency vs. Temperature



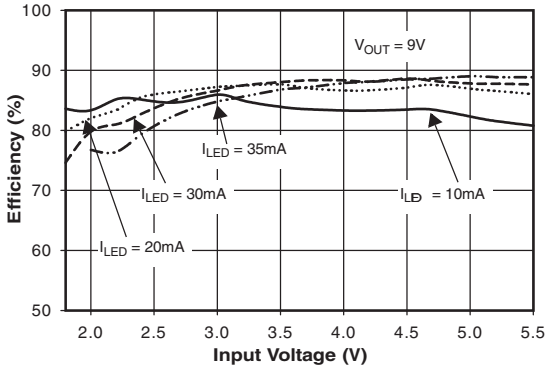
Load Current vs. Input Voltage



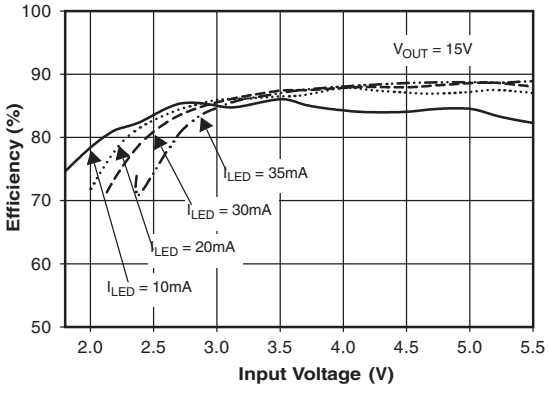
Start-Up Response



Efficiency vs. Input Voltage



Efficiency vs. Input Voltage



Block Diagram

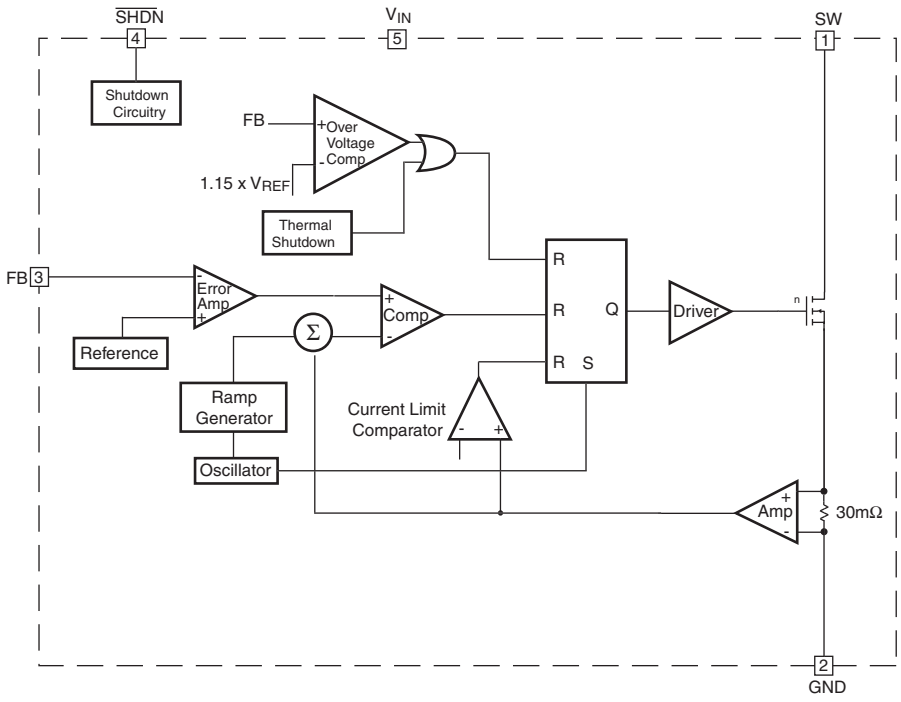


Figure 4. Block Diagram

Circuit Description

The FAN5330 is a pulse-width modulated (PWM) current-mode boost converter. The FAN5330 improves the performance of battery powered equipment by significantly minimizing the spectral distribution of noise at the input caused by the switching action of the regulator. In order to facilitate effective noise filtering, the switching frequency was chosen to be high, 1.5MHz. The device architecture is that of a current mode controller with an internal sense resistor connected in series with the N-channel switch. The voltage at the feedback pin tracks the output voltage at the cathode of the external Schottky diode (shown in the test circuit). The error amplifier amplifies the difference between the feedback voltage and the internal bandgap reference. The amplified error voltage serves as a reference voltage to the PWM comparator. The inverting input of the PWM comparator consists of the sum of two components: the amplified control signal received from the 30mΩ current sense resistor and the ramp generator voltage derived from the oscillator. The oscillator sets the latch, and the latch turns on the FET switch. Under normal operating conditions, the PWM comparator resets the latch and turns off the FET, thus terminating the pulse. Since the comparator input contains information about the output voltage and the control loop is arranged to form a negative feedback loop, the value of the peak inductor current will be adjusted to maintain regulation.

Every time the latch is reset, the FET is turned off and the current flow through the switch is terminated. The latch can be reset by other events as well. Over-current condition is monitored by the current limit comparator which resets the latch and turns off the switch instantaneously within each clock cycle.

Over-Voltage Protection

The voltage on the feedback pin is sensed by an OVP Comparator. When the feedback voltage is 15% higher than the nominal voltage, the OVP Comparator stops switching of the power transistor, thus preventing the output voltage from going higher.

Open-circuit protection

As in any current regulator, if the feedback loop is open, the output voltage increases until it is limited by some additional external circuitry. In the particular case of the FAN5330, the output voltage is limited by the switching transistor breakdown at around 45V, typically (assuming that C_{OUT} and the Schottky diode rating voltage are higher). Since at such high output voltage the output current is inherently limited by the discontinuous conduction mode, in most cases, the switching transistor enters non-destructive breakdown and the IC survives.

However, to ensure 100% protection for LED disconnection, we recommend limiting V_{OUT} with an external Zener diode or stopping the boost switching with an external voltage supervisory circuit.

Applications Information

Setting the Output Current

The internal reference (V_{REF}) is 110mV (Typical). The output current is set by a resistor divider R connected between FB pin and ground. The output current is given by

$$I_{LED} = \frac{V_{REF}}{R}$$

Inductor Selection

The inductor parameters directly related to device performances are saturation current and dc resistance. The FAN5330 operates with a typical inductor value of 10µH. The lower the dc resistance, the higher the efficiency. Usually a trade-off between inductor size, cost and overall efficiency is needed to make the optimum choice.

The inductor saturation current should be rated around 1.5A, which is the threshold of the internal current limit circuit. This limit is reached only during the start-up and with heavy load condition; when this event occurs the converter can shift over in discontinuous conduction mode due to the automatic turn-off of the switching transistor, resulting in higher ripple and reduced efficiency.

Some recommended inductors are suggested in the table below:

Inductor Value	Vendor	Part Number	Comment
10µH	TDK	SLF6025&-100M1R0	
10µH	MURATA	LQH66SN100M01C	Highest Efficiency
10µH	COOPER	SD414-100	Small Size

Table 1: Recommended Inductors

Capacitors Selection

For best performance, low ESR input and output capacitors are required. Ceramic capacitors of C_{IN} = 4.7µF and C_{OUT} = 0.47µF placed close to the IC pins, are required for optimum performance. The capacitances (C_{OUT}) may be reduced to 0.1µF, if higher ripple is acceptable. The output capacitor voltage rating should be according to the V_{OUT} setting. Some capacitors are suggested in the table below

Capacitor Value	Vendor	Part Number
0.47µF	Panasonic	ECJ-3YB1E474K
4.7µF	Murata	GRM21BR61A475K

Table 2: Recommended Capacitors

Diode Selection

The external diode used for rectification is usually a Schottky diode. Its average forward current and reverse voltage maximum ratings should exceed the load current and the voltage at the output of the converter respectively. A barrier Schottky diode such as BAT54 is preferred, due to its lower reverse current over the temperature range.

Care should be taken to avoid any short circuit of V_{OUT} to GND, even with the IC disabled, since the diode can be instantly damaged by the excessive current.

Brightness Control

1. Dimming Using PWM Logic Signal

A PWM signal applied to $\overline{SHDN}$ Table 5 on page 7 can control the LED's brightness in direct dependence with the duty cycle. The maximum frequency should not exceed 1kHz to ensure a linear dependence of the LED's average current. The amplitude of the PWM signal should be suitable to turn the FAN5333 ON and OFF.

Alternatively, a PWM logic signal can be used to switch a FET ON/OFF to change the resistance that sets the LED's current Table 6 on page 7. Adjusting the duty cycle from 0% to 100% results in varying the LED's current between I_{MIN} and I_{MAX}.

Where

$$I_{MIN} = \frac{V_{FB}}{R_{MIN}} \text{ and } I_{MAX} = \frac{V_{FB}}{R_{MIN} \| R_{SET}}$$

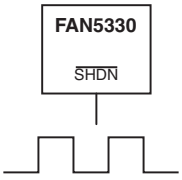


Figure 5. Dimming Using a PWM Signal

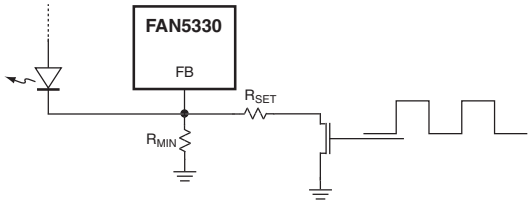


Figure 6. Dimming Using a PWM Logic Signal

2. Dimming Using DC Voltage

An external adjustable DC voltage Table 7 on page 7 between 0V to 2V can control the LED's current from 15mA to 0mA, respectively.

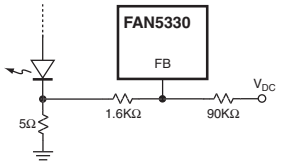


Figure 7. Dimming Using DC Voltage

3. Dimming Using Filtered PWM Signal

This method allows the use of a greater than 1kHz PWM frequency signal with minimum impact on the battery ripple. The filtered PWM signal Table 8 on page 8 acts as an adjustable DC voltage as long as its frequency is significantly higher than the corner frequency of the RC low pass filter.

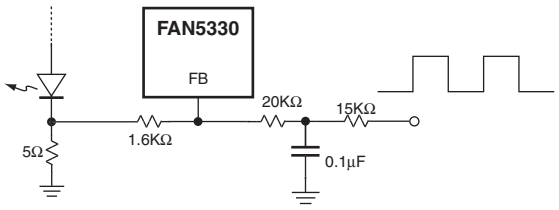


Figure 8. Dimming Using Filtered PWM Signal

Thermal Shutdown

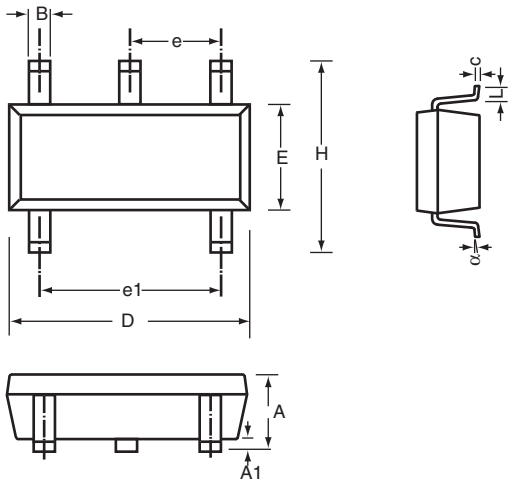
When the die temperature exceeds 150°C, a reset occurs and will remain in effect until the die cools to 130°C, at that time the circuit will be allowed to restart.

PCB Layout Recommendations

The inherently high peak currents and switching frequency of power supplies require careful PCB layout design. Therefore, use wide traces for high current paths and place the input capacitor, the inductor, and the output capacitor as close as possible to the integrated circuit terminals. The FB pin connection should be routed away from the inductor proximity to prevent RF coupling. A PCB with at least one ground plane connected to pin 2 of the IC is recommended. This ground plane acts as an electromagnetic shield to reduce EMI and parasitic coupling between components.

Mechanical Dimensions

5-Lead SOT-23



Symbol	Inches		Millimeters		Notes
	Min	Max	Min	Max	
A	.035	.057	.90	1.45	
A1	.000	.006	.00	.15	
B	.008	.020	.20	.50	
c	.003	.010	.08	.25	
D	.106	.122	2.70	3.10	
E	.059	.071	1.50	1.80	
e	.037 BSC		.95 BSC		
e1	.075 BSC		1.90 BSC		
H	.087	.126	2.20	3.20	
L	.004	.024	.10	.60	
α	0º	10º	0º	10º	

Ordering Information

Product Number	Package Type	Order Code
FAN5330	5-Lead SOT23	FAN5330SX

TRADEMARKS

The following are registered and unregistered trademarks Fairchild Semiconductor owns or is authorized to use and is not intended to be an exhaustive list of all such trademarks.

ACEx™	FAST®	ISOPLANAR™	PowerSaver™	SuperSOT™-8
ActiveArray™	FASTr™	LittleFET™	PowerTrench®	SyncFET™
Bottomless™	FPS™	MICROCOUPLER™	QFET®	TinyLogic®
Build it Now™	FRFET™	MicroFET™	QS™	TINYOPTO™
CoolFET™	GlobalOptoisolator™	MicroPak™	QT Optoelectronics™	TruTranslation™
CROSSVOLT™	GTO™	MICROWIRE™	Quiet Series™	UHC™
DOME™	HiSeC™	MSX™	RapidConfigure™	UltraFET®
EcoSPARK™	I²C™	MSXPro™	RapidConnect™	UniFET™
E²CMOS™	*i-Lo*™	OCX™	µSerDes™	VCX™
EnSigna™	ImpliedDisconnect™	OCXPro™	SILENT SWITCHER®	Wire™
FACT™	IntelliMAX™	OPTOLOGIC®	SMART START™	
FACT Quiet Series™		OPTOPLANAR™	SPM™	
Across the board. Around the world.™		PACMAN™	Stealth™	
The Power Franchise®		POP™	SuperFET™	
Programmable Active Droop™		Power247™	SuperSOT™-3	
		PowerEdge™	SuperSOT™-6	

DISCLAIMER

FAIRCHILD SEMICONDUCTOR RESERVES THE RIGHT TO MAKE CHANGES WITHOUT FURTHER NOTICE TO ANY PRODUCTS HEREIN TO IMPROVE RELIABILITY, FUNCTION OR DESIGN. FAIRCHILD DOES NOT ASSUME ANY LIABILITY ARISING OUT OF THE APPLICATION OR USE OF ANY PRODUCT OR CIRCUIT DESCRIBED HEREIN; NEITHER DOES IT CONVEY ANY LICENSE UNDER ITS PATENT RIGHTS, NOR THE RIGHTS OF OTHERS.

LIFE SUPPORT POLICY

FAIRCHILD'S PRODUCTS ARE NOT AUTHORIZED FOR USE AS CRITICAL COMPONENTS IN LIFE SUPPORT DEVICES OR SYSTEMS WITHOUT THE EXPRESS WRITTEN APPROVAL OF FAIRCHILD SEMICONDUCTOR CORPORATION.
As used herein:

1. Life support devices or systems are devices or systems which, (a) are intended for surgical implant into the body, or (b) support or sustain life, or (c) whose failure to perform when properly used in accordance with instructions for use provided in the labeling, can be reasonably expected to result in significant injury to the user.

2. A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

Rev. I16